



Correction: Efficient carrier transport in halide perovskites: theoretical perspectives

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Correction for 'Efficient carrier transport in halide perovskites: theoretical perspectives' by M. H. Du *et al.*, *J. Mater. Chem. A*, 2014, 2, 9091–9098.

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The author wishes to point out that in the abstract of the published article, there is an error in the following sentence: “Defect calculations show that, among native point defects (including vacancies, interstitials, and antisites), only iodine **vacancy** is a low-energy deep trap and non-radiative recombination centre.”

The corrected sentence should read: “Defect calculations show that, among native point defects (including vacancies, interstitials, and antisites), only iodine **interstitial** is a low-energy deep trap and non-radiative recombination centre.”

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

